Kazuaki Akaiwa

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/4742570/publications.pdf

Version: 2024-02-01

8	265	5	7
papers	citations	h-index	g-index
8	8	8	276
all docs	docs citations	times ranked	citing authors

#	Article	IF	CITATIONS
1	Electrical Properties of Snâ€Doped αâ€Ga ₂ O ₃ Films on mâ€Plane Sapphire Substrates Grown by Mist Chemical Vapor Deposition. Physica Status Solidi (A) Applications and Materials Science, 2020, 217, 1900632.	1.8	35
2	p-Type Nonpolar a-ZnO:N Thin Films on r-Sapphire Substrates Grown by Molecular Beam Epitaxy. Journal of Electronic Materials, 2020, 49, 4474-4478.	2.2	2
3	High-Gain Ultraviolet Avalanche Photodiodes Using a ZnSe-Based Organic–Inorganic Hybrid Structure. Journal of Electronic Materials, 2020, 49, 4589-4593.	2.2	4
4	Anisotropic phonon properties and effective electron mass in $\langle i \rangle \hat{l} \pm \langle i \rangle$ -Ga2O3. Applied Physics Letters, 2019, 114, .	3.3	11
5	Degradation and Its Control of Ultraviolet Avalanche Photodiodes Using PEDOT:PSS/ZnSSe Organic–Inorganic Hybrid Structure. Journal of Electronic Materials, 2018, 47, 4385-4387.	2.2	0
6	Conductivity control of Sn-doped α-Ga ₂ O ₃ thin films grown on sapphire substrates. Japanese Journal of Applied Physics, 2016, 55, 1202BA.	1.5	91
7	Electrical Conductive Corundum-Structured α-Ga ₂ O ₃ Thin Films on Sapphire with Tin-Doping Grown by Spray-Assisted Mist Chemical Vapor Deposition. Japanese Journal of Applied Physics, 2012, 51, 070203.	1.5	95
8	Electrical Conductive Corundum-Structured α-Ga ₂ O ₃ Thin Films on Sapphire with Tin-Doping Grown by Spray-Assisted Mist Chemical Vapor Deposition. Japanese Journal of Applied Physics, 2012, 51, 070203.	1.5	27